NSN 5961-01-445-8747

Diode Semiconductor Device - Page 1 of 1



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End Application:
F-15i
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Current Rating Per Characteristic:
100.00 amperes source cutoff current peak
Power Rating Per Characteristic:
1.0 watts small-signal input power, common-collector megawatts
Special Features:
Matched set of 3 diodes selected from jantx1n5555; vc @ 2.99 (10x1000 micro sec pulse) +/- 0.2 vdc
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0